TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

HN1A07F

Audio Frequency Small Power Amplifier Applications
Driver Stage Amplifier Applications
Switching applications

Excellent Currrent gain(h_{FE})linearity
 : h_{FE(2)} =25 (Min.) at V_{CE} = −6V I_C = −400mA

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	-50	V	
Collector-emitter voltage	V _{CEO}	-50	٧	
Emitter-base voltage	V _{EBO}	-5	V	
Collector current	IC	-500	mA	
Base current	ΙΒ	-100	mA	
Collector power dissipation	P _C *	300	mW	
Junction temperature	Tj	150	°C	
Storage temperature range	T _{stg}	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

Unit: mm 1.9 ± 0.2 1.EMITTER1 (E1)2.BASE1 3.COLLECTOR2 (C2) 4.EMITTER2 (E2) 5.BASE2 (B2) 6.COLLECTOR1 SM6 (C1)JEDEC JEITA **TOSHIBA** 2-3N1A

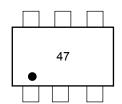
Weight: 0.015mg(typ.)

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

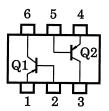
Electrical Characteristics (Ta = 25°C) (Q1,Q2 Common)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -50V$, $I_{E} = 0$	_	_	-100	nA
Emitter cut-off current	I _{EBO}	$V_{EB} = -5V, I_C = 0$	_	_	-100	nA
DC current gain —	h _{FE(1)}	$V_{CE} = -1V, I_{C} = -100 \text{mA}$	70	_	240	
	h _{FE(2)}	$V_{CE} = -1V, I_{C} = -400 \text{mA}$	25	_	_	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = -100mA, I _B = -10mA	_	-0.1	-0.25	V
Base-Emitter voltage	V _{BE}	$V_{CE} = -1V, I_{C} = -100 \text{mA}$	_	-0.8	-1.0	V
Transition frequency	f _T	$V_{CE} = -6V, I_{C} = -20mA$	_	200	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = -6V$, $I_{E} = 0$, $f = 1MHz$	_	13	_	pF

Marking

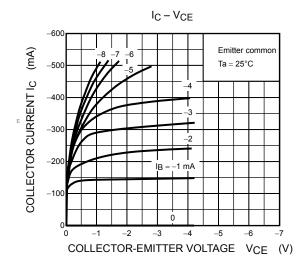


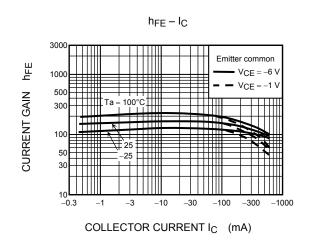
Equivalent Circuit (Top View)

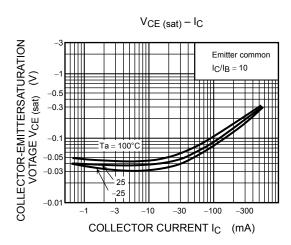


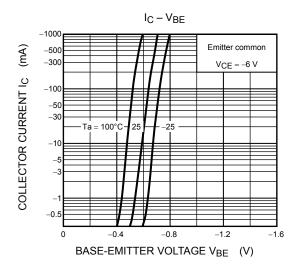
^{*}Total rating. Power dissipation per element should not exceed 200mW.

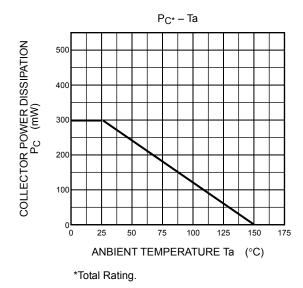
(Q1,Q2 Common)











2007-11-22

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20070701-EN GENERAL

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